



CRYSTAL OSCILLATOR (XO) (10 MHz to 1.4 GHz)

Features

- Available with any-rate output frequencies from 10 MHz to 945 MHz and select frequencies to 1.4 GHz
- 3rd generation DSPLL[®] with superior jitter performance
- 3x better frequency stability than SAW-based oscillators
- Internal fixed crystal frequency ensures high reliability and low aging
- Available CMOS, LVPECL, LVDS, and CML outputs
- 3.3, 2.5, and 1.8 V supply options
- Industry-standard 5 x 7 mm package and pinout
- Pb-free/RoHS-compliant



Applications

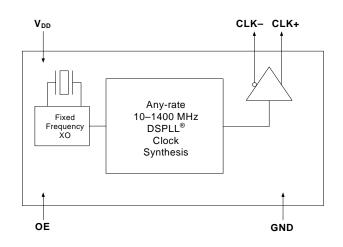
- SONET/SDH
- Networking
- SD/HD video

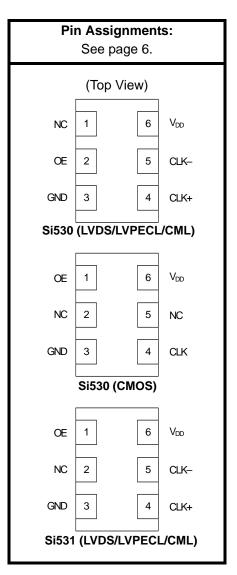
- Test and measurement
- Clock and data recovery
- FPGA/ASIC clock generation

Description

The Si530/531 XO utilizes Silicon Laboratories' advanced DSPLL[®] circuitry to provide a low jitter clock at high frequencies. The Si530/531 is available with any-rate output frequency from 10 to 945 MHz and select frequencies to 1400 MHz. Unlike a traditional XO, where a different crystal is required for each output frequency, the Si530/531 uses one fixed crystal to provide a wide range of output frequencies. This IC based approach allows the crystal resonator to provide exceptional frequency stability and reliability. In addition, DSPLL clock synthesis provides superior supply noise rejection, simplifying the task of generating low jitter clocks in noisy environments typically found in communication systems. The Si530/531 IC based XO is factory configurable for a wide variety of user specifications including frequency, supply voltage, output format, and temperature stability. Specific configurations are factory programmed at time of shipment, thereby eliminating long lead times associated with custom oscillators.

Functional Block Diagram





1. Electrical Specifications

Table 1. Recommended Operating Conditions

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Supply Voltage ¹	V _{DD}	3.3 V option	2.97	3.3	3.63	V
		2.5 V option	2.25	2.5	2.75	V
		1.8 V option	1.71	1.8	1.89	V
Supply Current	I _{DD}	Output enabled LVPECL CML LVDS CMOS	_ _ _	111 99 90 81	121 108 98 88	mA
		Tristate mode	_	60	75	mA
Output Enable (OE) ²		V _{IH}	0.75 x V _{DD}	_	_	V
		V _{IL}	_	_	0.5	V
Operating Temperature Range	T _A		-40	_	85	°C

Notes:

- 1. Selectable parameter specified by part number. See Section 3. "Ordering Information" on page 7 for further details.
- 2. OE pin includes a 17 k Ω pullup resistor to V_{DD} .

Table 2. CLK± Output Frequency Characteristics

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Nominal Frequency ^{1,2}	f _O	LVPECL/LVDS/CML	10	_	945	MHz
		CMOS	10	_	160	MHz
Initial Accuracy	f _i	Measured at +25 °C at time of shipping	_	±1.5	_	ppm
Temperature Stability ^{1,3}			-7 -20 -50	_ _ _	+7 +20 +50	ppm
Aging		Frequency drift over first year		_	±3	ppm
	f _a	Frequency drift over 20 year life	_	_	±10	ppm

Notes:

2

- 1. See Section 3. "Ordering Information" on page 7 for further details.
- 2. Specified at time of order by part number. Also available in frequencies from 970 to 1134 MHz and 1213 to 1417 MHz.
- 3. Selectable parameter specified by part number.
- **4.** Time from powerup or tristate mode to f_O.

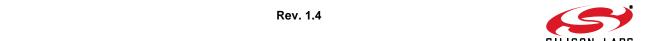


Table 2. CLK± Output Frequency Characteristics (Continued)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Total Stability		Temp stability = ±7 ppm	_	_	±20	ppm
		Temp stability = ±20 ppm	_	_	±31.5	ppm
		Temp stability = ±50 ppm	_	_	±61.5	ppm
Powerup Time ⁴	tosc		_	_	10	ms

Notes:

- 1. See Section 3. "Ordering Information" on page 7 for further details.
- 2. Specified at time of order by part number. Also available in frequencies from 970 to 1134 MHz and 1213 to 1417 MHz.
- 3. Selectable parameter specified by part number.
- **4.** Time from powerup or tristate mode to f_O.

Table 3. CLK± Output Levels and Symmetry

Parameter	Symbol	Test C	ondition	Min	Тур	Max	Unit
LVPECL Output Option ¹	Vo	mid	l-level	V _{DD} – 1.42	_	V _{DD} – 1.25	V
	V _{OD}	swin	g (diff)	1.1	_	1.9	V_{PP}
	V _{SE}	swing (sir	ngle-ended)	0.55	_	0.95	V_{PP}
LVDS Output Option ²	Vo	mid	l-level	1.125	1.20	1.275	V
	V _{OD}	swin	g (diff)	0.5	0.7	0.9	V _{PP}
CML Output Option ²	V -	2.5/3.3 V op	otion mid-level	_	V _{DD} – 1.30	_	V
	Vo	1.8 V option	on mid-level	_	V _{DD} – 0.36	_	V
	V	2.5/3.3 V opt	2.5/3.3 V option swing (diff)		1.50	1.90	V _{PP}
	V _{OD}	1.8 V optio	n swing (diff)	0.35	0.425	0.50	V _{PP}
CMOS Output Option ³	V _{OH}	I _{OH} =	32 mA	0.8 x V _{DD}	_	V_{DD}	V
	V _{OL}	I _{OL} =	32 mA	_	_	0.4	V
Rise/Fall time (20/80%)	$t_{R,} t_{F}$	LVPECL/	LVDS/CML	_	_	350	ps
		CMOS with C _L = 15 pF		_	1	_	ns
Symmetry (duty cycle)	SYM	LVPECL: (diff) LVDS: CMOS:	V _{DD} – 1.3 V 1.25 V (diff) V _{DD} /2	45	_	55	%

Notes:

- 1. 50Ω to V_{DD} 2.0 V. 2. R_{term} = 100Ω (differential).
- 3. $C_L = 15 pF$



Table 4. CLK± Output Phase Jitter

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Phase Jitter (RMS) ¹	фЈ	12 kHz to 20 MHz (OC-48)	_	0.25	0.40	ps
for F _{OUT} ≥ 500 MHz		50 kHz to 80 MHz (OC-192)		0.26	0.37	ps
Phase Jitter (RMS) ¹	фЈ	12 kHz to 20 MHz (OC-48)	_	0.36	0.50	ps
for F _{OUT} of 125 to 500 MHz		50 kHz to 80 MHz (OC-192) ²	_	0.34	0.42	ps
Phase Jitter (RMS)	фЈ	12 kHz to 20 MHz (OC-48) ²	_	0.62	_	ps
for F _{OUT} of 10 to 160 MHz CMOS Output Only		50 kHz to 20 MHz ²	_	0.61	_	ps

Notes:

- 1. Refer to AN256 for further information.
- 2. Max offset frequencies: 80 MHz for FOUT \geq 250 MHz, 20 MHz for 50 MHz \leq FOUT <250 MHz, 2 MHz for 10 MHz \leq FOUT <50 MHz.

Table 5. CLK± Output Period Jitter

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Period Jitter*	J _{PER}	RMS	_	2	_	ps	
		Peak-to-Peak	_	14	_	ps	
*Note: Any output mode, including CMOS, LVPECL, LVDS, CML. N = 1000 cycles. Refer to AN279 for further information.							

Table 6. CLK± Output Phase Noise (Typical)

Offset Frequency (f)	120.00 MHz	156.25 MHz	622.08 MHz	Unit
	LVDS	LVPECL	LVPECL	
100 Hz	-112	-105	-97	
1 kHz	-122	-122	-107	
10 kHz	-132	-128	-116	
100 kHz	-137	-135	-121	dBc/Hz
1 MHz	-144	-144	-134	
10 MHz	-150	-147	-146	
100 MHz	n/a	n/a	-148	

Table 7. Environmental Compliance

The Si530/531 meets the following qualification test requirements.

Parameter	Conditions/Test Method
Mechanical Shock	MIL-STD-883, Method 2002
Mechanical Vibration	MIL-STD-883, Method 2007
Solderability	MIL-STD-883, Method 2003
Gross & Fine Leak	MIL-STD-883, Method 1014
Resistance to Solder Heat	MIL-STD-883, Method 2036
Moisture Sensitivity Level	J-STD-020, MSL1
Contact Pads	Gold over Nickel

Table 8. Thermal Characteristics

(Typical values TA = 25 °C, V_{DD} = 3.3 V)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Thermal Resistance Junction to Ambient	$\theta_{\sf JA}$	Still Air	_	84.6	_	°C/W
Thermal Resistance Junction to Case	θЈС	Still Air	_	38.8	_	°C/W
Ambient Temperature	T _A		-40	_	85	°C
Junction Temperature	TJ		_		125	°C

Table 9. Absolute Maximum Ratings¹

Parameter	Symbol	Rating	Unit
Maximum Operating Temperature	T _{AMAX}	85	°C
Supply Voltage, 1.8 V Option	V _{DD}	-0.5 to +1.9	V
Supply Voltage, 2.5/3.3 V Option	V _{DD}	-0.5 to +3.8	V
Input Voltage (any input pin)	V _I	-0.5 to V _{DD} + 0.3	V
Storage Temperature	T _S	-55 to +125	°C
ESD Sensitivity (HBM, per JESD22-A114)	ESD	2500	V
Soldering Temperature (Pb-free profile) ²	T _{PEAK}	260	°C
Soldering Temperature Time @ T _{PEAK} (Pb-free profile) ²	t _P	20–40	seconds

Notes:

- Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Functional
 operation or specification compliance is not implied at these conditions. Exposure to maximum rating conditions for
 extended periods may affect device reliability.
- 2. The device is compliant with JEDEC J-STD-020C. Refer to Si5xx Packaging FAQ available for download at www.silabs.com/VCXO for further information, including soldering profiles.



2. Pin Descriptions

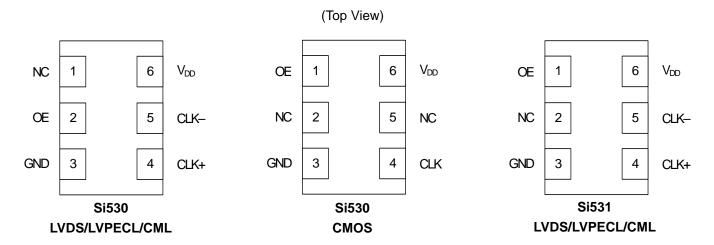


Table 10. Pinout for Si530 Series

Pin	Symbol	LVDS/LVPECL/CML Function	CMOS Function				
1	OE (CMOS only)*	No connection	Output enable 0 = clock output disabled (outputs tristated) 1 = clock output enabled				
2	OE (LVPECL,LVDS, CML)*	Output enable 0 = clock output disabled (outputs tristated) 1 = clock output enabled	No connection				
3	GND	Electrical and Case Ground	Electrical and Case Ground				
4	CLK+	Oscillator Output	Oscillator Output				
5	CLK-	Complementary Output	No connection				
6	V_{DD}	Power Supply Voltage	Power Supply Voltage				
*Note	*Note: OE includes a 17 kΩ pullup resistor to V _{DD} .						

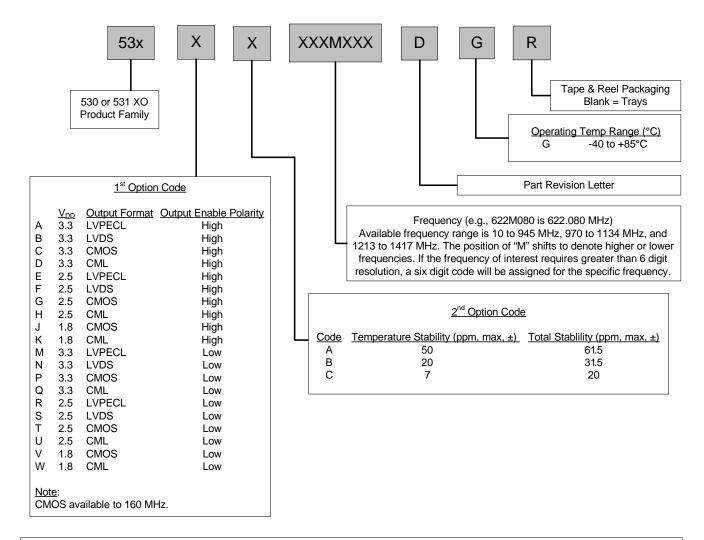
Table 11. Pinout for Si531 Series

Pin	Symbol	LVDS/LVPECL/CML Function					
		Output enable					
1	OE (LVPECL, LVDS, CML)*	0 = clock output disabled (outputs tristated)					
		1 = clock output enabled					
2	No connection	No connection					
3	GND	Electrical and Case Ground					
4	CLK+	Oscillator Output					
5	CLK-	Complementary output					
6	V_{DD}	Power Supply Voltage					
*Note:	*Note: OE includes a 17 $k\Omega$ pullup resistor to V_{DD} .						



3. Ordering Information

The Si530/531 XO supports a variety of options including frequency, temperature stability, output format, and V_{DD} . Specific device configurations are programmed into the Si530/531 at time of shipment. Configurations can be specified using the Part Number Configuration chart below. Silicon Laboratories provides a web browser-based part number configuration utility to simplify this process. Refer to www.silabs.com/VCXOPartNumber to access this tool and for further ordering instructions. The Si530 and Si531 XO series are supplied in an industry-standard, RoHS compliant, 6-pad, 5 x 7 mm package. The Si531 Series supports an alternate OE pinout (pin #1) for the LVPECL, LVDS, and CML output formats. See Tables 10 and 11 for the pinout differences between the Si530 and Si531 series.



Example P/N: 530AB622M080DGR is a $5 \times 7 \times 7 \times 10^{-2}$ in a 6 pad package. The frequency is 622.080×10^{-2} MHz, with a 3.3×10^{-2} supply, LVPECL output, and Output Enable active high polarity. Temperature stability is specified as $\pm 20 \times 10^{-2}$ ppm. The part is specified for -40×10^{-2} to $\pm 85 \times 10^{-2}$ c ambient temperature range operation and is shipped in tape and reel format.

Figure 1. Part Number Convention



4. Outline Diagram and Suggested Pad Layout

Figure 2 illustrates the package details for the Si530/531. Table 12 lists the values for the dimensions shown in the illustration.

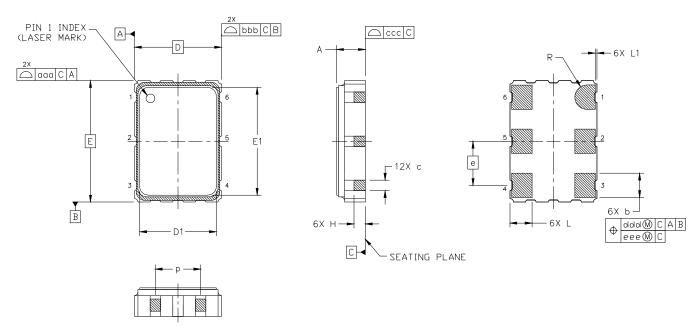


Figure 2. Si530/531 Outline Diagram

Table 12. Package Diagram Dimensions (mm)

Dimension	Min	Nom	Max
Α	1.50	1.65	1.80
b	1.30	1.40	1.50
С	0.50	0.60	0.70
D	5.00 BSC		
D1	4.30	4.40	4.50
е	2.54 BSC		
Е	7.00 BSC		
E1	6.10	6.20	6.30
Н	0.55	0.65	0.75
L	1.17	1.27	1.37
L1	0.05	0.10	0.15
р	1.80	_	2.60
R	0.70 REF		
aaa	0.15		
bbb	0.15		
CCC	0.10		
ddd	0.10		
eee	0.05		
Notes:			

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.



5. Si530/Si531 Mark Specification

Figure 3 illustrates the mark specification for the Si530/Si531. Table 13 lists the line information.

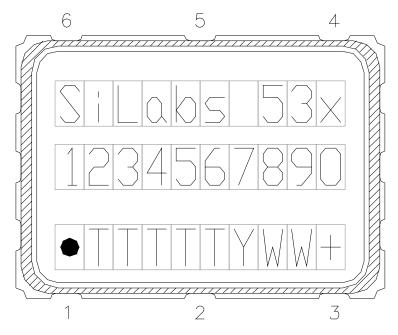


Figure 3. Mark Specification

Table 13. Si53x Top Mark Description

Line	Position	Description		
1	1–10	"SiLabs"+ Part Family Number, $53x$ (First 3 characters in part number where $x = 0$ indicates a 530 device and $x = 1$ indicates a 531 device).		
2	1–10	Si530, Si531: Option1 + Option2 + Freq(7) + Temp Si532, Si533, Si534, Si530/Si531 w/ 8-digit resolution: Option1 + Option2 + ConfigNum(6) + Temp		
3	Trace Code			
	Position 1	Pin 1 orientation mark (dot)		
	Position 2	Product Revision (D)		
	Position 3–6	Tiny Trace Code (4 alphanumeric characters per assembly release instructions)		
	Position 7	Year (least significant year digit), to be assigned by assembly site (ex: 2007 = 7)		
	Position 8–9	Calendar Work Week number (1–53), to be assigned by assembly site		
	Position 10	"+" to indicate Pb-Free and RoHS-compliant		



6. 6-Pin PCB Land Pattern

Figure 4 illustrates the 6-pin PCB land pattern for the Si530/531. Table 14 lists the values for the dimensions shown in the illustration.

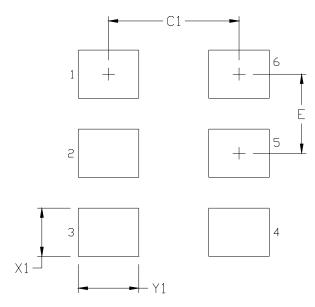


Figure 4. Si530/531 PCB Land Pattern

Table 14. PCB Land Pattern Dimensions (mm)

Dimension	(mm)
C1	4.20
E	2.54
X1	1.55
Y1	1.95

Notes:

General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
- 3. This Land Pattern Design is based on the IPC-7351 guidelines.
- **4.** All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μ m minimum, all the way around the pad.

Stencil Design

- **1.** A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1.

Card Assembly

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



DOCUMENT CHANGE LIST

Revision 0.4 to Revision 0.5

- Updated Table 1, "Recommended Operating Conditions," on page 2.
 - Added maximum supply current specifications.
 - Specified relationship between temperature at startup and operation temperature.
- Updated Table 4, "CLK± Output Phase Jitter," on page 4 to include maximum rms jitter generation specifications and updated typical rms jitter specifications.
- Added Table 6, "CLK± Output Phase Noise (Typical)," on page 4.
- Added Output Enable active polarity as an option in Figure 1, "Part Number Convention," on page 7.

Revision 0.5 to Revision 1.0

- Updated Note 3 in Table 1, "Recommended Operating Conditions," on page 2.
- Updated Figure 1, "Part Number Convention," on page 7.

Revision 1.0 to Revision 1.1

- Updated Table 1, "Recommended Operating Conditions," on page 2.
 - Device maintains stable operation over –40 to +85 °C operating temperature range.
 - Supply current specifications updated for revision D.
- Updated Table 2, "CLK± Output Frequency Characteristics," on page 2.
 - Added specification for ±20 ppm lifetime stability (±7 ppm temperature stability) XO.
- Updated Table 3, "CLK± Output Levels and Symmetry," on page 3.
 - Updated LVDS differential peak-peak swing specifications.
- Updated Table 4, "CLK± Output Phase Jitter," on page 4.
- Updated Table 5, "CLK± Output Period Jitter," on page 4.
 - Revised period jitter specifications.
- Updated Table 9, "Absolute Maximum Ratings¹," on page 5 to reflect the soldering temperature time at 260 °C is 20–40 sec per JEDEC J-STD-020C.
- Updated 3. "Ordering Information" on page 7.
 - Changed ordering instructions to revision D.
- Added 5. "Si530/Si531 Mark Specification" on page 9.

Revision 1.1 to Revision 1.2

- Updated 2.5 V/3.3 V and 1.8 V CML output level specifications for Table 3 on page 3.
- Added footnotes clarifying max offset frequency test conditions for Table 4 on page 4.
- Added CMOS phase jitter specs to Table 4 on page 4.
- Removed the words "Differential Modes: LVPECL/LVDS/CML" in the footnote referring to AN256 in Table 4 on page 4.
- Separated 1.8 V, 2.5 V/3.3 V supply voltage specifications in Table 9 on page 5.
- Updated and clarified Table 9 on page 5 to include the "Moisture Sensitivity Level" and "Contact Pads" rows.
- Updated Figure 3 on page 9 and Table 13 on page 9 to reflect specific marking information. Previously, Figure 3 was generic.

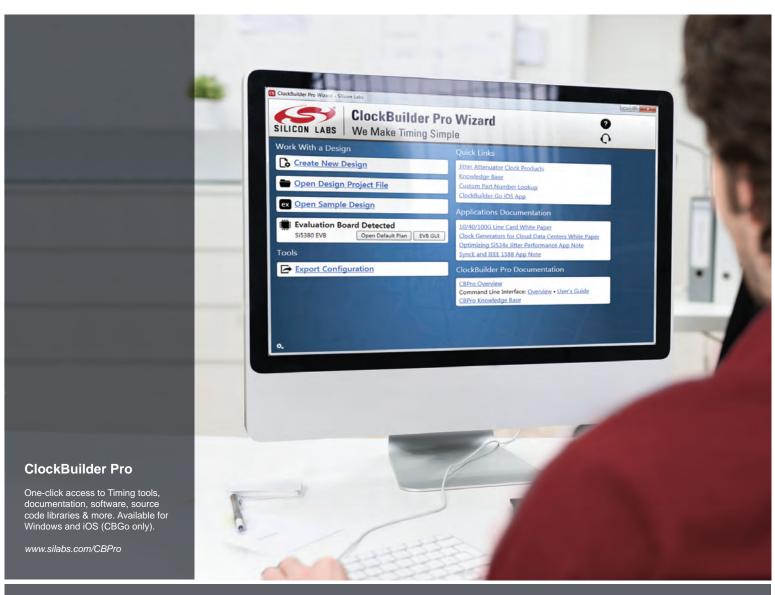
Revision 1.2 to Revision 1.3

 Added Table 8, "Thermal Characteristics," on page 5.

Revision 1.3 to Revision 1.4

- Revised Figure 2 and Table 12 on page 8 to reflect current package outline diagram.
- Revised Figure 4 and Table 14 on page 10 to reflect the recommended PCB land pattern.













Disclaimer

Silicon Laboratories intends to provide customers with the latest, accurate, and in-depth documentation of all peripherals and modules available for system and software implementers using or intending to use the Silicon Laboratories products. Characterization data, available modules and peripherals, memory sizes and memory addresses refer to each specific device, and "Typical" parameters provided can and do vary in different applications. Application examples described herein are for illustrative purposes only. Silicon Laboratories reserves the right to make changes without further notice and limitation to product information, specifications, and descriptions herein, and does not give warranties as to the accuracy or completeness of the included information. Silicon Laboratories shall have no liability for the consequences of use of the information supplied herein. This document does not imply or express copyright licenses granted hereunder to design or fabricate any integrated circuits. The products must not be used within any Life Support System without the specific written consent of Silicon Laboratories. A "Life Support System" is any product or system intended to support or sustain life and/or health, which, if it fails, can be reasonably expected to result in significant personal injury or death. Silicon Laboratories products are generally not intended for military applications. Silicon Laboratories products shall under no circumstances be used in weapons of mass destruction including (but not limited to) nuclear, biological or chemical weapons, or missiles capable of delivering such weapons.

Trademark Information

Silicon Laboratories Inc., Silicon Laboratories, Silicon Labs, SiLabs and the Silicon Labs logo, CMEMS®, EFM, EFM32, EFR, Energy Micro, Energy Micro logo and combinations thereof, "the world's most energy friendly microcontrollers", Ember®, EZLink®, EZMac®, EZRadio®, EZRadioPRO®, DSPLL®, ISOmodem ®, Precision32®, ProSLIC®, SiPHY®, USBXpress® and others are trademarks or registered trademarks of Silicon Laboratories Inc. ARM, CORTEX, Cortex-M3 and THUMB are trademarks or registered trademarks of ARM Holdings. Keil is a registered trademark of ARM Limited. All other products or brand names mentioned herein are trademarks of their respective holders.



Silicon Laboratories Inc. 400 West Cesar Chavez Austin, TX 78701 USA

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Silicon Laboratories:

```
530CA12M0000DG 530CA50M0000DG 530GA25M0000DG 530CA33M0000DG 531AA25M0000DG
530CC20M0000DG 531AC156M250DG 531FC155M520DG 530AA64M2000DG 531FA162M000DG Si5319A-C-GM
 Si5319B-C-GM Si5319C-C-GM 530PA10M2400DG 530AC80M0000DG 530AC46M0800DG 530AC184M320DG
530AA66M6600DG 530AB400M000DG 531BA250M000DG 531BA200M000DG 530CA25M0000DG Si5316-C-GM
531FC000199DG 530AB51M2000DG 530CC56M2800DG 530BA80M0000DG 531AC1220M00DG
530AA166M000DG 531FA200M000DG 531FA250M000DG 530JC80M0000DG 530CC24M5760DG
530JA98M3040DG 531FB156M250DG 530AA95M5730DG 530PA128M000DG 530NB19M4400DG
531AA720M000DG 530CC14M0000DG 530PA140M000DG 530JA100M000DG 530CB22M5792DG
530CB24M5760DG 530CC122M880DG 530CB122M880DG 530CA61M4400DG 531KB800M000DG
530CB80M0000DG 530AA80M0000DG 530BA159M375DG 531BA98M0000DG 530AA100M000DG
530BC125M000DG 530CA28M6000DG
                              531BB100M000DG
                                             531FA125M000DG 530GA22M5792DG
530GA24M5760DG 530CC25M0000DG 530GB80M0000DG 531BA106M250DG 530NA65M0000DG
530GB45M1584DG 530GB49M1520DG 530BB50M0000DG
                                             530AA321M740DG 530NB24M5760DG
530FC100M000DG 530SC100M000DG 530SC300M000DG 530VA100M000DG 530NC400M000DG
530VC50M0000DG 530VC150M000DG 530SC200M000DG
                                             530PC150M000DG 530VC100M000DG
530GB160M000DG 530HC100M000DG 530HC125M000DG 531BA159M375DG 530AB90M0000DG
530AC125M000DG
               530AC90M0000DG
                              530AB10M0000DG
                                             530AB135M000DG 530AB93M3333DG
530AC10M0000DG
               530AC135M000DG
                              530AC93M3333DG
                                             530CB10M0000DG
                                                            530CB27M0000DG
530BB470M000DG 530CC11M2896DG 531BB125M000DG 530HB156M250DG 530KB156M250DG
530PB12M2880DG 530PB16M9344DG
```